

TO-92L Plastic-Encapsulate Transistors

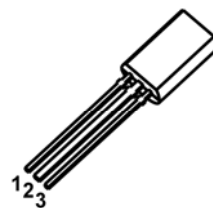
KTC3228 TRANSISTOR (NPN)

FEATURES

- High Voltage
- Large Collector Current Capability
- Complementary to KTA1275

TO - 92L

1. EMITTER
2. COLLECTOR
3. BASE



MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	160	V
V_{CEO}	Collector-Emitter Voltage	160	V
V_{EBO}	Emitter-Base Voltage	6	V
I_C	Collector Current	1	A
P_C	Collector Power Dissipation	750	mW
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient	167	$^{\circ}\text{C/W}$
T_j	Junction Temperature	150	$^{\circ}\text{C}$
T_{stg}	Storage Temperature	-55~+150	$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS ($T_a=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=1\text{mA}, I_E=0$	160			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=10\text{mA}, I_B=0$	160			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=1\text{mA}, I_C=0$	6			V
Collector cut-off current	I_{CBO}	$V_{CB}=150\text{V}, I_E=0$			1	μA
Emitter cut-off current	I_{EBO}	$V_{EB}=6\text{V}, I_C=0$			1	μA
DC current gain	h_{FE}	$V_{CE}=5\text{V}, I_C=200\text{mA}$	60		320	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=500\text{mA}, I_B=50\text{mA}$			1.5	V
Base-emitter voltage	V_{BE}	$V_{CE}=5\text{V}, I_C=5\text{mA}$	0.45		0.75	V
Collector output capacitance	C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=1\text{MHz}$			20	pF
Transition frequency	f_T	$V_{CE}=5\text{V}, I_C=200\text{mA}$	20			MHz

CLASSIFICATION OF h_{FE}

RANK	R	O	Y
RANGE	60-120	100-200	160-320